

Photomicrosensor (Transmissive)

EE-SX1140

Deep Slot, Wide-width/Terminal Type (Slot Width: 14 mm)

- Deep slot type (Light axis height: 13.5 mm)
- Terminal for PCB mounting
- Includes screw mounting holes (M3)

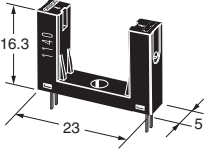

 Be sure to read *Safety Precautions* on Page 3.

RoHS Compliant



Ordering Information

Photomicrosensor

Appearance	Sensing method	Connecting method	Sensing distance	Aperture size (H x W) (mm)	Output type	Model	Minimum packing unit (Unit: pcs)
	Transmissive (slot type)	Terminal for PCB mounting	 14 mm (Slot width)	Both emitting side and detecting side 2 x 1.5	Phototransistor	EE-SX1140	1

Note: Order in multiples of minimum packing unit.

Ratings, Characteristics and Exterior Specifications

Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Rated value	Unit
Emitter			
Forward current	I _F	50*1	mA
Pulse forward current	I _{FP}	1*2	A
Reverse voltage	V _R	4	V
Detector			
Collector-Emitter voltage	V _{CEO}	30	V
Emitter-Collector voltage	V _{ECO}	—	V
Collector current	I _C	20	mA
Collector dissipation	P _C	100*3	mW
Operating temperature	T _{opr}	-25 to 85	°C
Storage temperature	T _{stg}	-30 to 100	°C
Soldering temperature	T _{sol}	260*3	°C

*1. Refer to the temperature rating chart if the ambient temperature exceeds 25°C.

*2. Pulse width ≤ 10 μs, Repeated 100 Hz

*3. Complete soldering within 10 seconds.

Exterior Specifications

Connecting method	Weight (g)	Material
		Case
Terminal for PCB mounting	0.7	Polycarbonate

Electrical and Optical Characteristics (Ta = 25°C)

Item	Symbol	Value			Unit	Condition
		MIN.	TYP.	MAX.		
Emitter						
Forward voltage	V _F	—	1.2	1.5	V	I _F = 30 mA
Reverse current	I _R	—	0.01	10	μA	V _R = 4 V
Peak emission wavelength	λ _P	—	940	—	nm	I _F = 20 mA
Detector						
Light current	I _L	0.4	—	—	mA	I _F = 20 mA, V _{CE} = 10 V
Dark current	I _D	—	2	200	nA	V _{CE} = 10 V, 0 lx
Leakage current	I _{LEAK}	—	—	—	μA	—
Collector-Emitter saturated voltage	V _{CE (sat)}	—	0.1	0.4	V	I _F = 20 mA, I _L = 0.1 mA
Peak spectral sensitivity wavelength	λ _P	—	850	—	nm	V _{CE} = 10 V
Rising time	t _r	—	4	—	μs	V _{CC} = 5 V, R _L = 100 Ω, I _L = 5 mA
Falling time	t _f	—	4	—	μs	V _{CC} = 5 V, R _L = 100 Ω, I _L = 5 mA

Engineering Data (Reference Value)

Fig 1. Forward Current vs. Collector Dissipation Temperature Rating

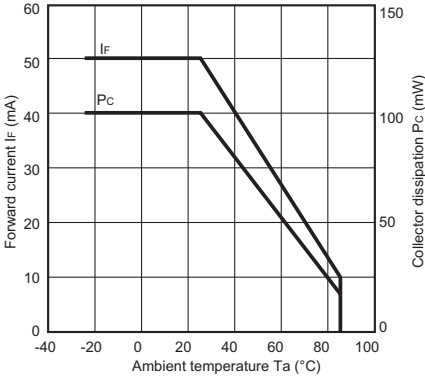


Fig 2. Forward Current vs. Forward Voltage Characteristics (Typical)

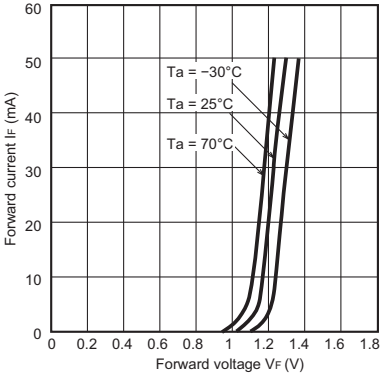


Fig 3. Light Current vs. Forward Current Characteristics (Typical)

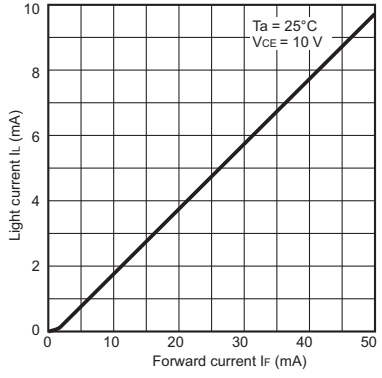


Fig 4. Light Current vs. Collector-Emitter Voltage Characteristics (Typical)

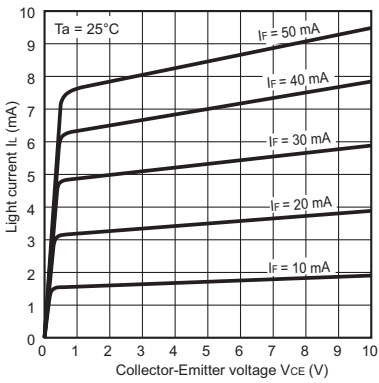


Fig 5. Relative Light Current vs. Ambient Temperature Characteristics (Typical)

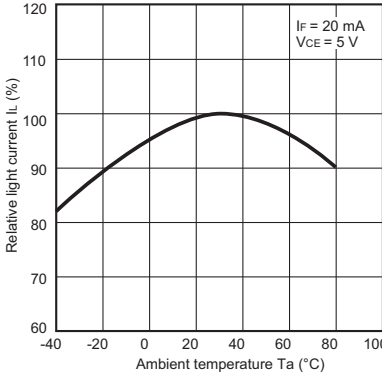


Fig 6. Dark Current vs. Ambient Temperature Characteristics (Typical)

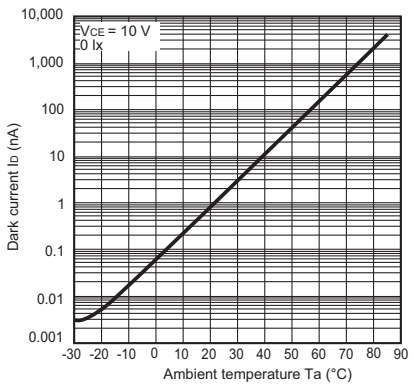


Fig 7. Response Time vs. Load Resistance Characteristics (Typical)

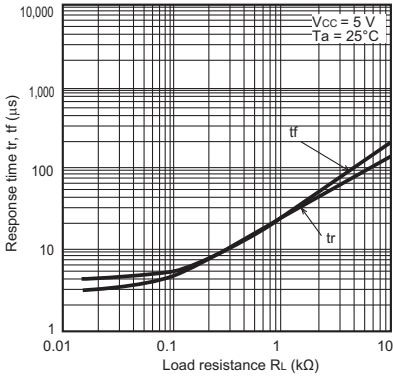


Fig 8. Sensing Position Characteristics (Typical)

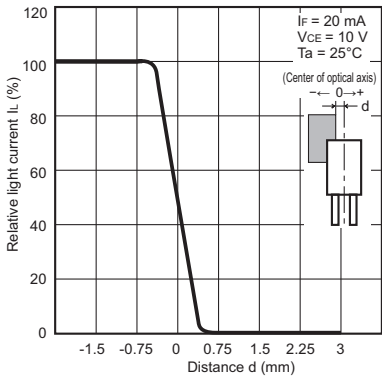


Fig 9. Sensing Position Characteristics (Typical)

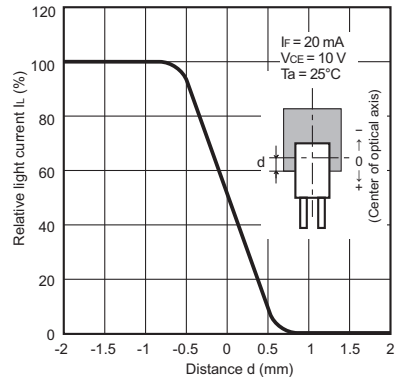
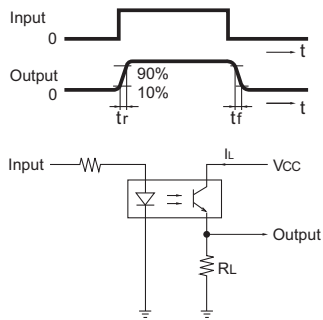


Fig 10. Response Time Measurement Circuit



Safety Precautions

To ensure safe operation, be sure to read and follow the Instruction Manual provided with the Sensor.

⚠ CAUTION

This product is not designed or rated for ensuring safety of persons either directly or indirectly. Do not use it for such purposes.

Precautions for Correct Use

Do not use the product in atmospheres or environments that exceed product ratings.

Precautions for Safe Use

Do not use the product with a voltage or current that exceeds the rated range.
Applying a voltage or current that is higher than the rated range may result in explosion or fire.

Do not miswire such as the polarity of the power supply voltage.
Otherwise the product may be damaged or it may burn.

This product does not resist water. Do not use the product in places where water or oil may be sprayed onto the product.

Dimensions and Internal Circuit

(Unit: mm)

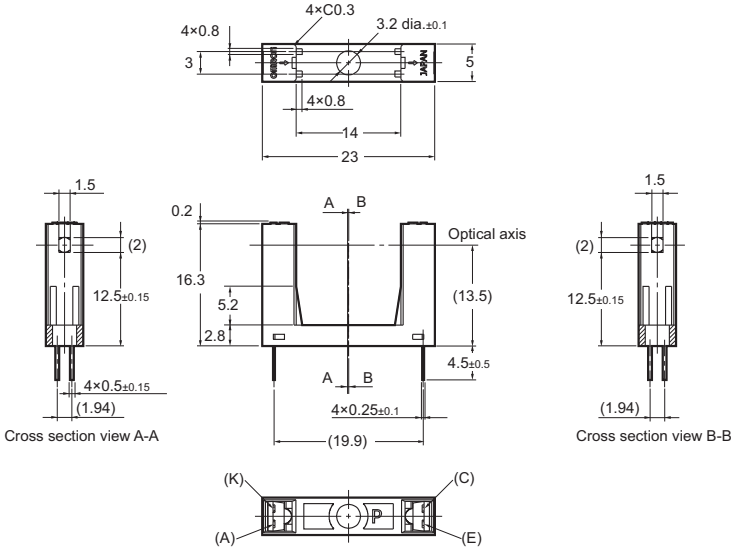
Photomicrosensor

EE-SX1140

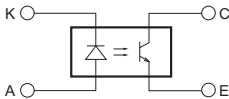


Aperture size (H x W)

Emitter	Detector
2 x 1.5	2 x 1.5



Internal circuit



Terminal No.	Name
A	Anode
K	Cathode
C	Collector
E	Emitter

Unless otherwise specified, the tolerances are as shown below.

Dimensions	Tolerance
3 mm max.	±0.3
3 < mm ≤ 6	±0.375
6 < mm ≤ 10	±0.45
10 < mm ≤ 18	±0.55
18 < mm ≤ 30	±0.65

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